DATA SHEET

BFQ166
NPN video transistor

Product specification
Supersedes data of November 1995
File under Discrete Semiconductors, SC05

1997 Oct 02

Philips
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NPN video transistor BFQ166

FEATURES

- Low output capacitance
- High gain bandwidth
- Good thermal stability
- Gold metallization ensures excellent reliability
- High current applicability
- Surface mounting.

APPLICATIONS

- Video amplifier cascode driver in high-resolution colour graphics monitors.

DESCRIPTION

NPN video transistor in a SOT223 plastic package.

PINNING

PIN	DESCRIPTION
1	emitter
2	base
3	emitter
4	collector

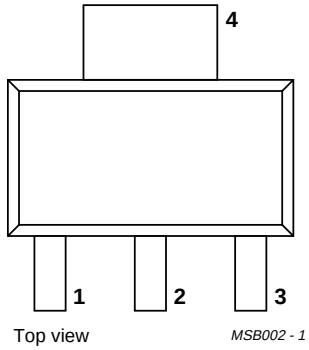


Fig.1 Simplified outline (SOT223).

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	–	20	V
V_{CER}	collector-emitter voltage	R_{BE} = 100 Ω	–	–	19	V
I_C	collector current (DC)		–	–	500	mA
P_{tot}	total power dissipation	$T_s \leq 105$ °C; note 1	–	–	2	W
h_{FE}	DC current gain	I_C = 300 mA; V_{CE} = 5 V; see Fig.4	50	60	–	
f_T	transition frequency	I_C = 300 mA; V_{CE} = 5 V; f = 100 MHz; T_{amb} = 25 °C	1	–	–	GHz

Note

1. T_s is the temperature at the soldering point of the collector lead.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	20	V
V_{CEO}	collector-emitter voltage	open base	–	10	V
V_{CER}	collector-emitter voltage	R_{BE} = 100 Ω	–	19	V
V_{EBO}	emitter-base voltage	open collector	–	3	V
I_C	collector current (DC)		–	500	mA
P_{tot}	total power dissipation	$T_s \leq 105$ °C; note 1; see Fig.3	–	2	W
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	175	°C

Note

1. T_s is the temperature at the soldering point of the collector lead.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\text{-}s}$	thermal resistance from junction to soldering point	T_s = 105 °C; P_{tot} = 2 W; notes 1 and 2	35	K/W

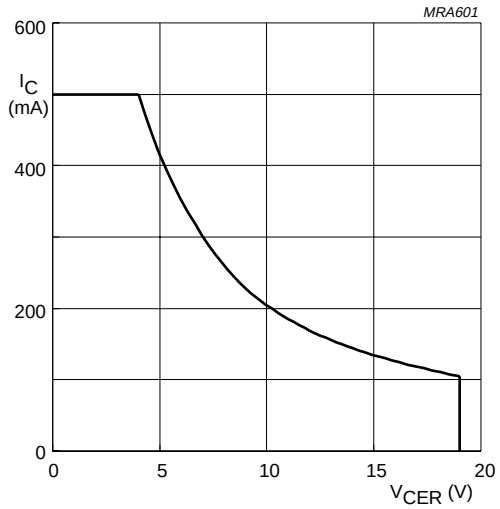
Notes

1. T_s is the temperature at the soldering point of the collector lead.
2. Device mounted on a printed-circuit board measuring 40 × 40 × 1 mm (collector pad 35 × 17 mm).

CHARACTERISTICS

T_j = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{(BR)CBO}$	collector-base breakdown voltage	I_C = 5 mA; I_E = 0	20	–	–	V
$V_{(BR)CER}$	collector-emitter breakdown voltage	I_C = 10 mA; R_{BE} = 100 Ω	19	–	–	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	I_C = 10 mA; I_B = 0	10	–	–	V
I_{CES}	collector-emitter cut-off current	V_{CE} = 10 V; V_{BE} = 0	–	–	100	µA
h_{FE}	DC current gain	I_C = 300 mA; V_{CE} = 5 V; see Fig.4	50	60	–	
C_c	collector capacitance	$I_E = i_e$ = 0; V_{CB} = 5 V; f = 1 MHz	–	4.5	–	pF
C_{cb}	collector-base capacitance	$I_C = i_c$ = 0; V_{CB} = 5 V; f = 1 MHz; see Fig.6	–	3.2	–	pF
f_T	transition frequency	I_C = 300 mA; V_{CE} = 5 V; f = 100 MHz; T_{amb} = 25 °C; see Fig.5	1	–	–	GHz



$R_{BE} \leq 100\ \Omega$.

Fig.2 DC SOAR.

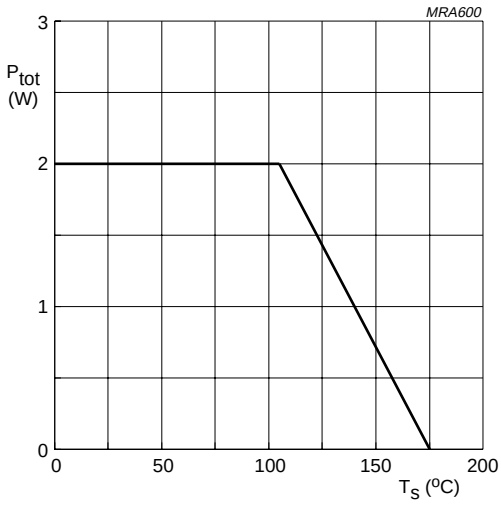
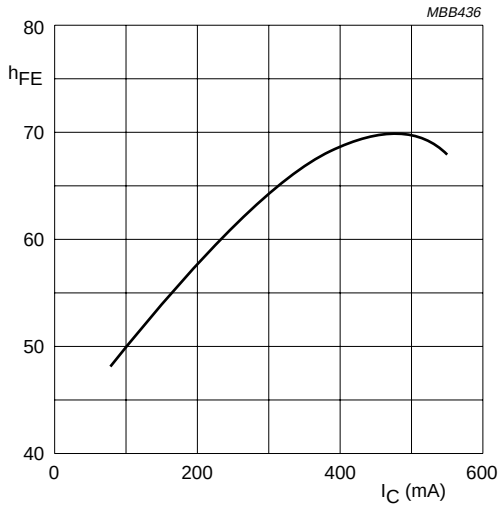
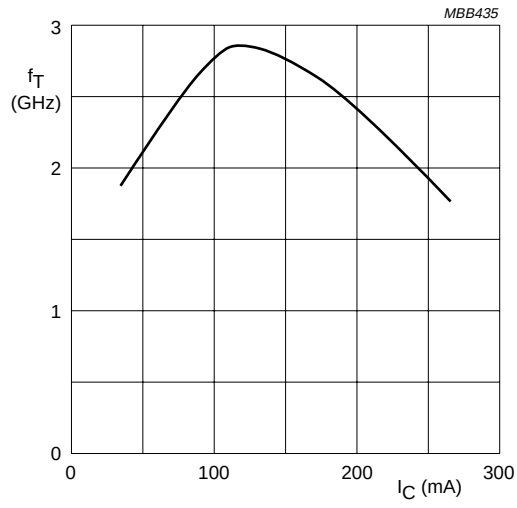


Fig.3 Power derating curve.



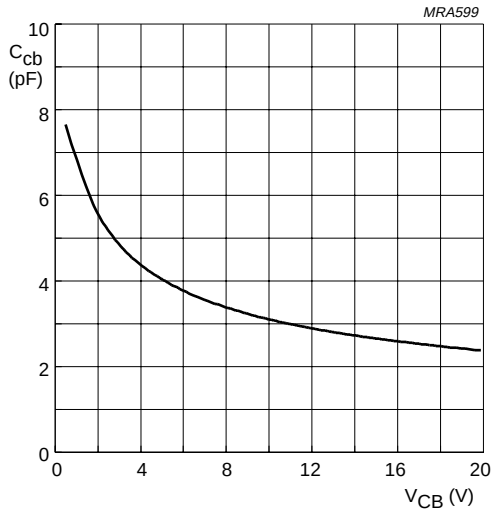
$V_{CE} = 5$ V.

Fig.4 DC current gain as a function of collector current; typical values.



$V_{CE} = 5$ V; $T_{amb} = 25$ °C.

Fig.5 Transition frequency as a function of collector current; typical values.

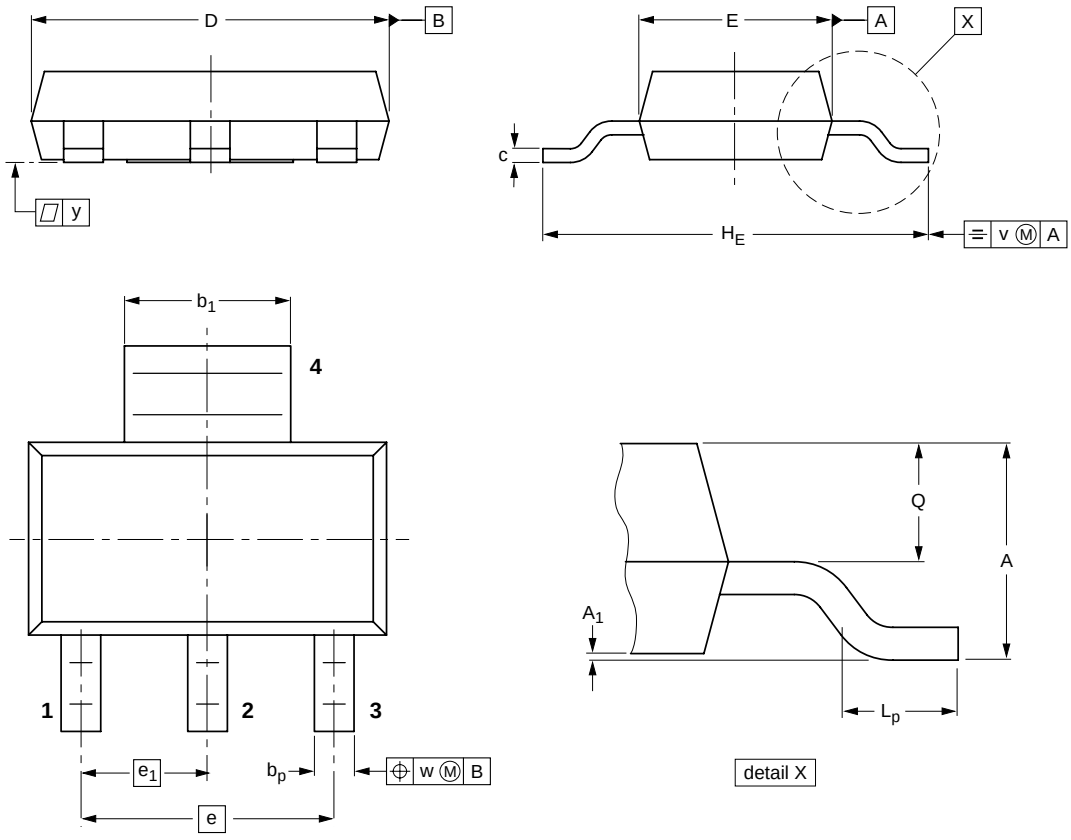


I_C = 0; f = 1 MHz.

Fig.6 Collector-base capacitance as a function of collector-base voltage; typical values.

PACKAGE OUTLINE

Plastic surface mounted package; collector pad for good heat transfer; 4 leads **SOT223**



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1	b_p	b_1	c	D	E	e	e_1	H_E	L_p	Q	v	w	y
mm	1.8 1.5	0.10 0.01	0.80 0.60	3.1 2.9	0.32 0.22	6.7 6.3	3.7 3.3	4.6	2.3	7.3 6.7	1.1 0.7	0.95 0.85	0.2	0.1	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT223						~~96-11-11~~ 97-02-28

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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